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Dated: June 16, 2004

Signature: _____

(Michael R. Hull)

Docket No.: 29925/37672
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Letters Patent of:
Young-Hun Bae et al.

Patent No.: 6,716,760

Issued: April 6, 2004

For: METHOD FOR FORMING A GATE OF A
HIGH INTEGRATION SEMICONDUCTOR
DEVICE INCLUDING FORMING AN
ETCHING PREVENTION OR ETCH STOP
LAYER AND AN ANTI- REFLECTION
LAYER

Certificate
JUN 24 2004
of Correction

REQUEST FOR CERTIFICATE OF CORRECTION PURSUANT TO 37 CFR 1.322

MS Post Issue
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Upon reviewing the above-identified patent, Patentees noted typographical errors which should be corrected.

Title Page
First Column
Field 54 (Title):

Line 5, Please delete "AND" and insert --AND AN--.

Support for the above Title correction can be found on page 2 of the Examiner's Amendment dated October 6, 2003.

24 JUN 2004

Title Page

First Column

Field (75) Inventors:

Line 1, Please delete "Icheon" and replace with --Gyeonggi-do--.

Line 2, Please delete " Pyungtaek" and replace with --Gyeonggi-do--.

Support for the above Inventors' corrections can be found on page 2 of the Declaration for Patent Application and Power of Attorney signed on March 15, 2002 (filed March 28, 2002).

In the Claims:

Claim 1,

Column 4, Lines 10-12

Please delete "depositing an etching prevention layer wherein the anti-reflection layer and the etching prevention layer are formed of different materials, on the resultant structure;" and replace with --depositing an etching prevention layer on the resultant structure;-- .

Support for the above Claim correction can be found on page 3 of the Amendment dated August 28, 2003 (filed August 28, 2003) and on page 2 of the Examiner's Amendment dated October 6, 2003.

Claim 1,

Column 4, Lines 13-14

Please delete "depositing an anti-reflection layer on the etching prevention layer;" and replace with --depositing an anti-reflection layer on the etching prevention layer wherein the anti-reflection layer and the etching prevention layer are formed of different materials,--.

Support for the above Claim correction can be found on page 3 of the Amendment dated August 28, 2003 (filed August 28, 2003) and on page 2 of the Examiner's Amendment dated October 6, 2003.

Claim 5,

Column 4, Lines 38-40

Please delete "depositing an etching prevention layer wherein the anti-reflection layer and the etching prevention layer are formed of different materials, on the nitride layer," and replace with --depositing an etching prevention layer on the nitride layer,--.

Support for the above Claim correction can be found on page 4 of the Amendment dated August 28, 2003 (filed August 28, 2003) and the Examiner's Amendment, dated October 6, 2003.

Claim 5,
Column 4, Lines 41-42

Please delete "depositing an anti-reflection layer on the etching prevention layer;" and replace with --depositing an anti-reflection layer on the etching prevention layer wherein the anti-reflection layer and the etching prevention layer are formed of different materials,--.

Support for the above Claim correction can be found on page 4 of the Amendment dated August 28, 2003 (filed August 28, 2003) and the Examiner's Amendment, dated October 6, 2003.

The errors were not in the application as filed by applicants; accordingly no fee is required.

Transmitted herewith is a proposed Certificate of Correction effecting such amendment. Patentee respectfully solicits the granting of the requested Certificate of Correction.

Dated: June 16, 2004

Respectfully submitted,

By 

Michael R. Hull

Registration No.: 35,902

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CERTIFICATE OF CORRECTION**

PATENT NO. : 6,716,760
DATED : April 6, 2004
INVENTOR(S) : Young-Hun Bae et al.

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Page 1 of 3

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